NSN 5962-01-447-5766

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View Online at https://aerobasegroup.com/nsn/5962-01-447-5766

Body Length:
1.060 inches
Body Width:
0.310 inches
Body Height:
0.185 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Burn in and electrostatic sensitive and monolithic and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
16 input
Current Rating Per Characteristic:
70.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Product Name:
Tm clamp circuitry
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
10.00 nanoseconds input
Memory Device Type:
Pal
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
20 printed circuit
Shelf Life:
N/a
Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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